N-Channel Silicon MOSFET



2SK2627

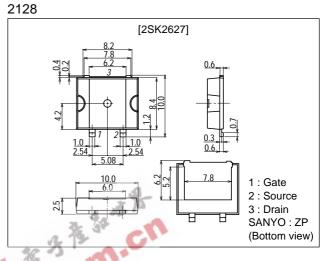
# **Ultrahigh-Speed Switching Applications**

# Features

- · Low ON-resistance.
- $\cdot$  Low Qg.

# **Package Dimensions**

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at $Ta = 25^{\circ}C$

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Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		600	V
Gate-to-Source Voltage	VGSS		±30	V
Drain Current (DC)	lp		5	А
Drain Current (Pulse)	I <sub>DP</sub> PW≤10μs	, duty cycle≤1%	20	А
Allowable Power Dissipation	PD Tc=25°C		40	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### **Electrical Characteristics** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings			Unit		
			min	typ	max	Unit		
Drain-to-Source Breakdown Voltage	V <sub>(BR)</sub> DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	600			V		
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =600V, V <sub>GS</sub> =0			1.0	mA		
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±30V, V <sub>DS</sub> =0			±100	nA		
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	3.5		5.5	V		
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =2.5A	1.5	3.0		S		
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =2.5A, V <sub>GS</sub> =15V		1.5	2.0	Ω		
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		700		pF		
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		220		pF		
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		110		pF		
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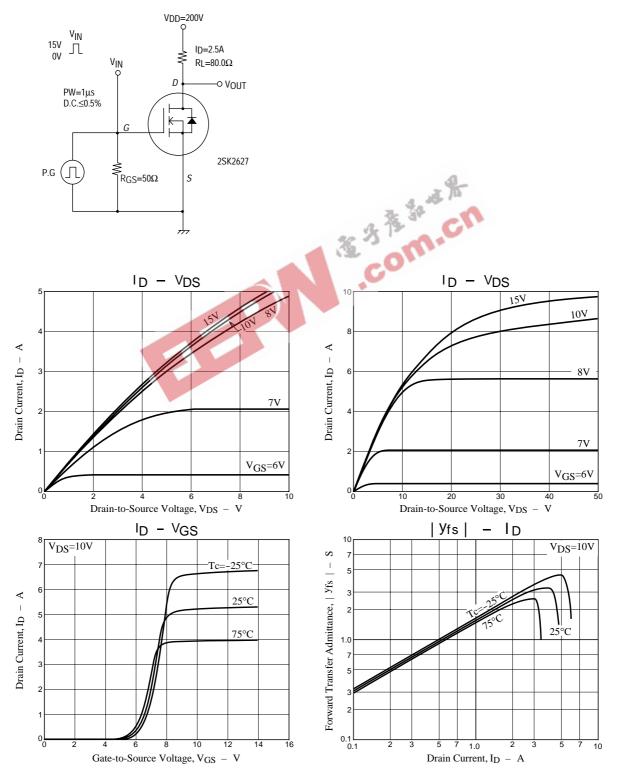
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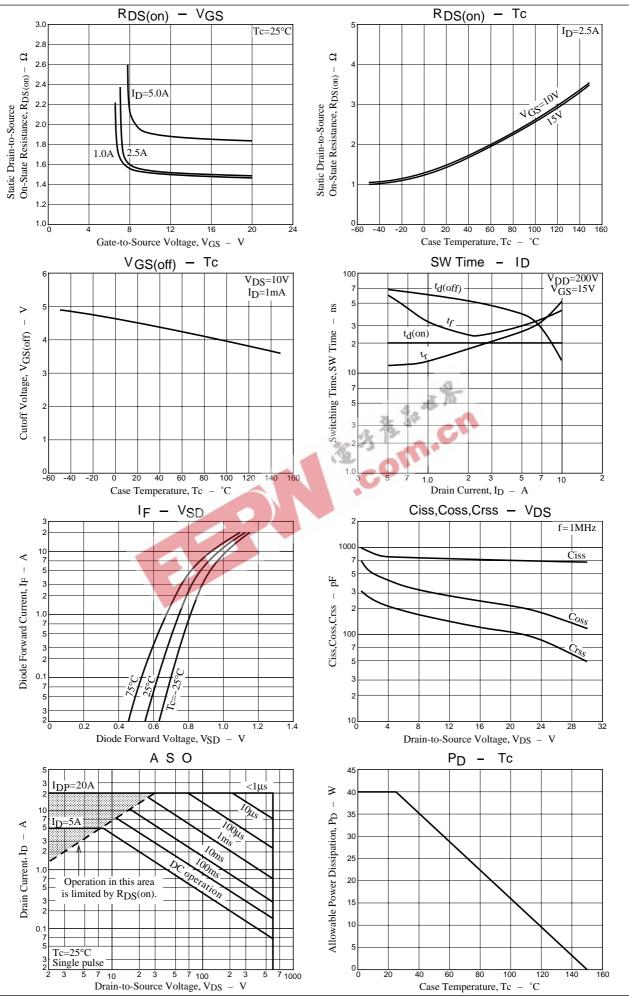
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

#### Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		20		nC
Turn-ON Delay Time	<sup>t</sup> d(on)	See specified Test Circuit		20		ns
Rise Time	tr	See specified Test Circuit		20		ns
Turn-OFF Delay Time	<sup>t</sup> d(off)	See specified Test Circuit		50		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		25		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =5A, V <sub>GS</sub> =0		0.87	1.2	V

# Switching Time Test Circuit





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